

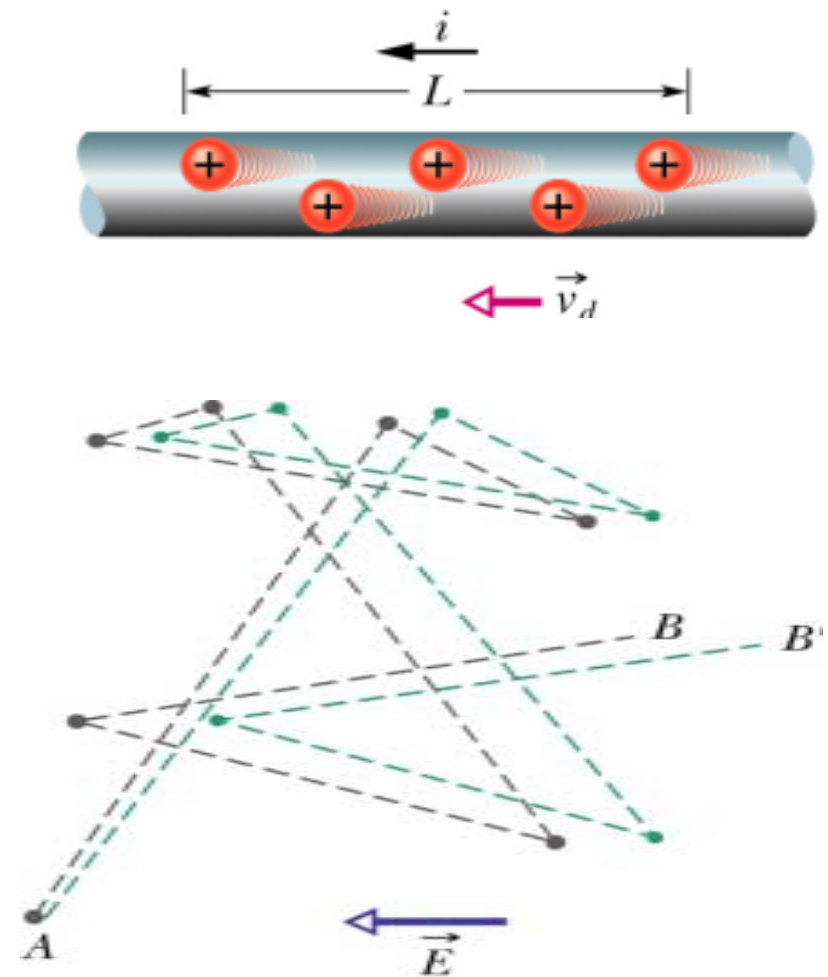
# Lecture 13

## Chapter 27

### Current and Resistance

# Current (10)

- Electrons have random motion with speeds  $\approx 10^6$  m/s – gray line
- Drift speeds are tiny  $v_d \approx 10^{-5}$  or  $10^{-4}$  m/s
- Motion of electrons in  $E$  is due to both random motion and drift speed

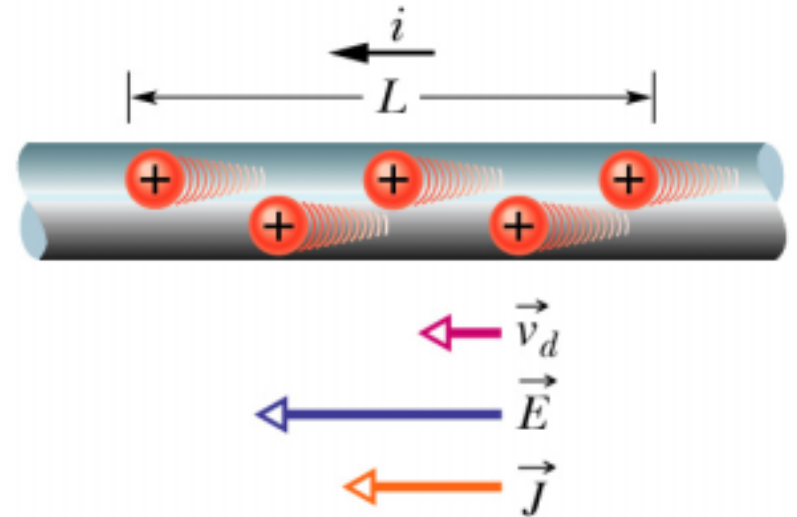


# Current (11)

- Relate the drift speed,  $v_d$ , to the charge density
- Assume  $J$  uniform across cross-sectional area  $A$
- Total charge in length  $L$  is

$$q = ne(AL)$$

- All charges move with same drift speed so charge moves through any cross section in time

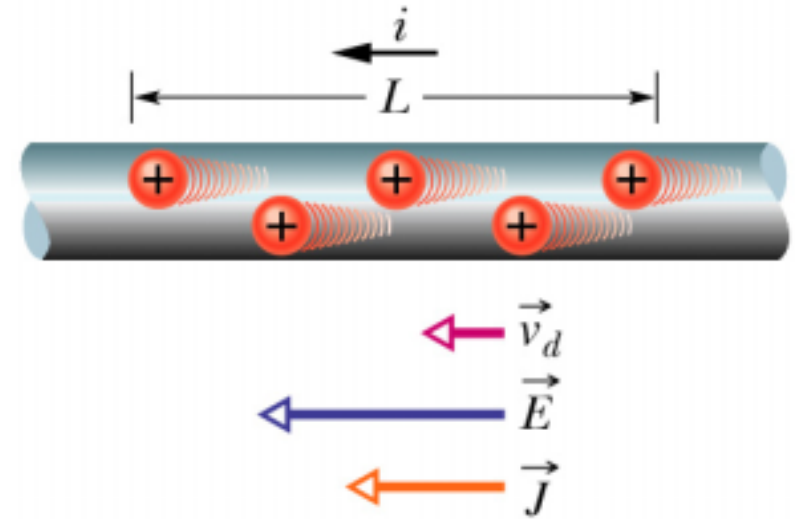


$$t = \frac{L}{v_d}$$

# Current (12)

- Current is given by

$$i = \frac{q}{t} = \frac{neAL}{L/v_d} = neAv_d$$



- Solving for drift speed

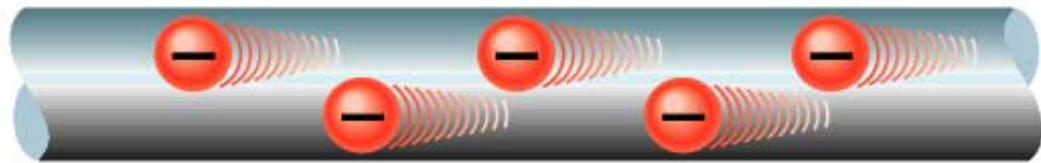
$$v_d = \frac{i}{neA} \quad \text{BUT} \quad J = \frac{i}{A}$$

$$\vec{v}_d = \frac{\vec{J}}{ne}$$

- $J, v_d$  same dir. for + charge
- $J, v_d$  opposite dir. for - charge

# Current (13)

- Checkpoint #2 – Conduction electrons move leftward in wire. The following are leftward or rightward?



- A) Current,  $i$ , is  
rightward
- B) Current density,  $J$ , is  
rightward
- C)  $E$  field in wire is  
rightward

# Current (14)

- Different types of conductors, i.e. glass and copper, give very different  $i$  for the same  $V$

- Define this characteristic as **resistance**

$$R = \frac{V}{i}$$

- SI unit is ohm,  $\Omega$

$$1\Omega = 1V / A$$

- A **resistor** is a device used to provide a specified resistance in a circuit

# Current (15)

- Rearrange resistance relation
- For given  $V$  greater  $R$  , smaller  $i$

$$i = \frac{V}{R}$$

- Macroscopic quantities  $V$ ,  $i$  and  $R$  work well for electrical measurements
- Use microscopic quantities  $E$  ,  $J$  , and  $\rho$  when talk about electrical properties of materials

# Current (16)

- Resistivity,  $\rho$ , of a material is defined as

- SI unit is  $\Omega \cdot \text{m}$

$$\rho = \frac{E}{J}$$

- Conversely speak of a material's conductivity,  $\sigma$

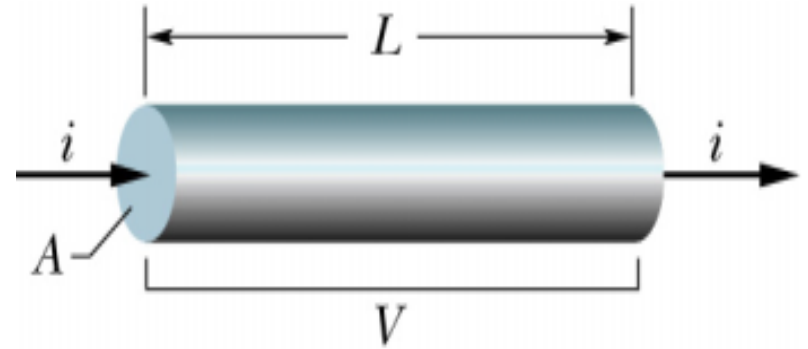
- SI unit is  $(\Omega \cdot \text{m})^{-1}$

$$\sigma = \frac{1}{\rho}$$



# Current (17)

- Know  $\rho$  of material can calculate  $R$  for a length of wire of that material

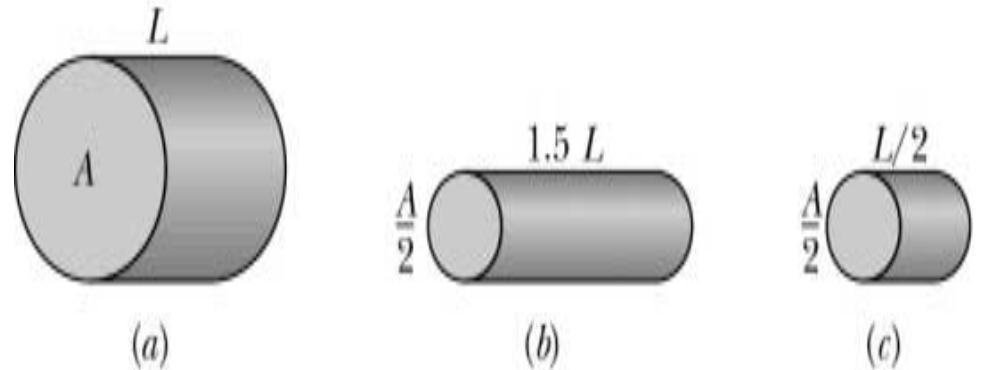


$$\rho = \frac{E}{J} \quad \text{BUT} \quad E = \frac{\Delta V}{\Delta s} = \frac{V}{L} \quad J = \frac{i}{A}$$

$$\rho = \frac{V/L}{i/A} = \frac{V A}{i L} \quad \text{BUT} \quad R = \frac{V}{i} \quad \text{SO} \quad R = \rho \frac{L}{A}$$

# Current (18)

- Checkpoint #3 – 3 copper conductors with same applied  $V$ . Rank  $i$  through them, greatest first.



$$R = \rho \frac{L}{A}$$

$$R_a = \rho \frac{L}{A}$$

$$R_b = \rho \frac{1.5L}{A/2} = \rho \frac{3L}{A}$$

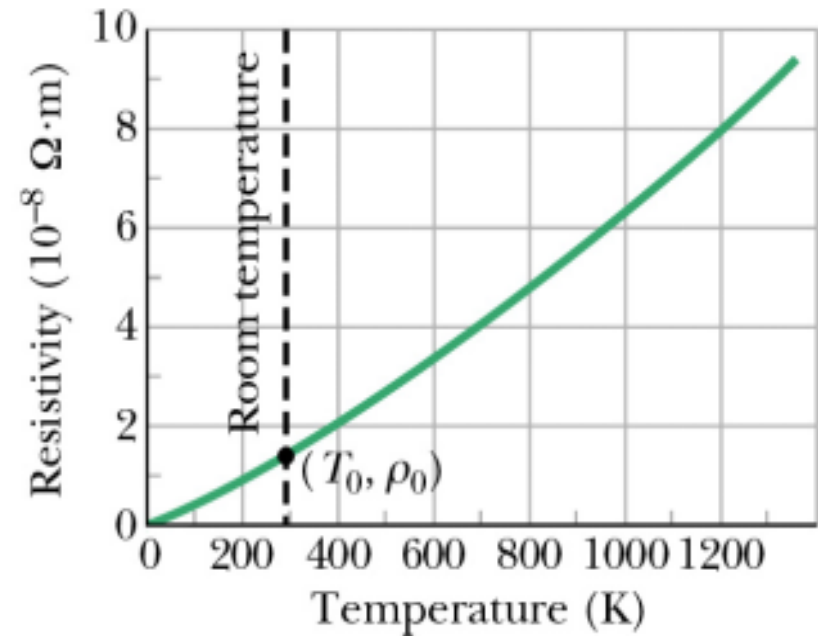
$$R_c = \rho \frac{L/2}{A/2} = \rho \frac{L}{A}$$

$$i = \frac{V}{R}$$

a and c tie, then b

# Current (19)

- Resistivity,  $\rho$ , varies with temperature due to thermal vibrations
- For metals, relation is fairly linear – e.g. copper →
- $T_0$  and  $\rho_0$  are reference points measured at room temperature
- $\alpha$  is temperature coefficient of resistivity



$$\rho - \rho_0 = \rho_0 \alpha (T - T_0)$$

# Current (20)

- Resistivities for some common materials
- Typically for metals – if temperature increases,  $\rho$  increases
- Glass will conductor at high temperatures

Material	Resistivity, $\rho$
Copper	$1.69 \times 10^{-8}$
Silicon	$2.5 \times 10^3$
Silicon, n-type	$8.7 \times 10^{-4}$
Glass	$10^{10} - 10^{14}$

# Current (21)

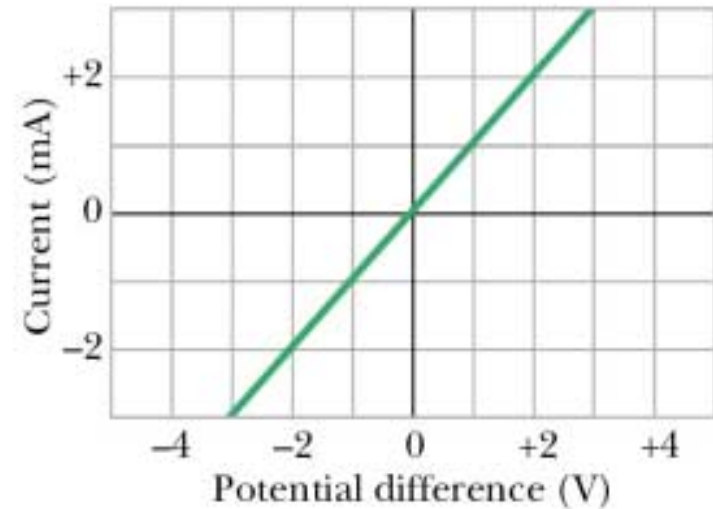
- So far have assumed that  $R$  is independent of the magnitude and polarity of the applied  $V$
- This is known as **Ohm's law**
- Ohm's law is not generally valid, but it is a good empirical rule for most systems

$$R = \frac{V}{i}$$

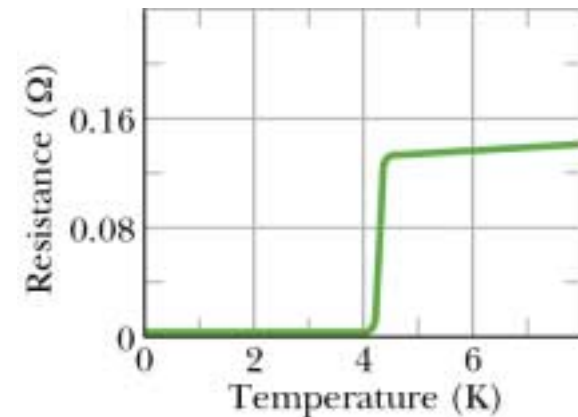
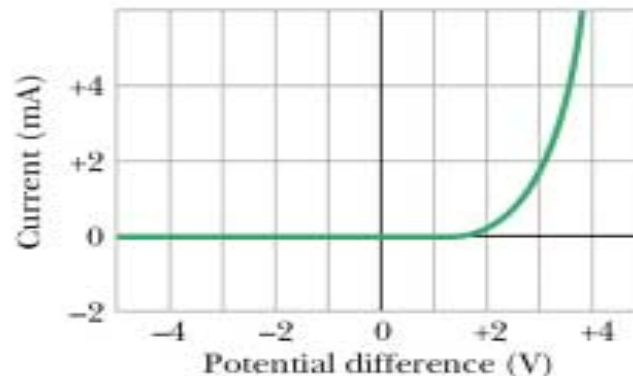
$$V = iR$$

# Current (22)

- Ohm's law says:  $R$  is independent of size and direction of  $V$
- Slope of  $i$  vs.  $V$  is a straight line

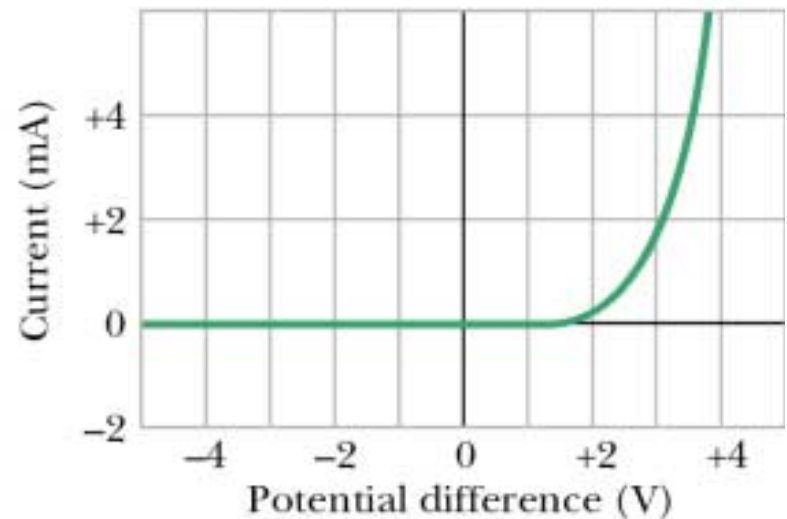
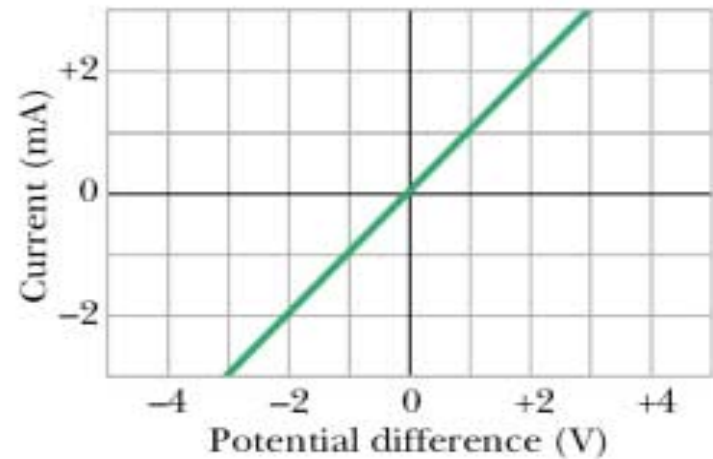


- What about these other graphs?



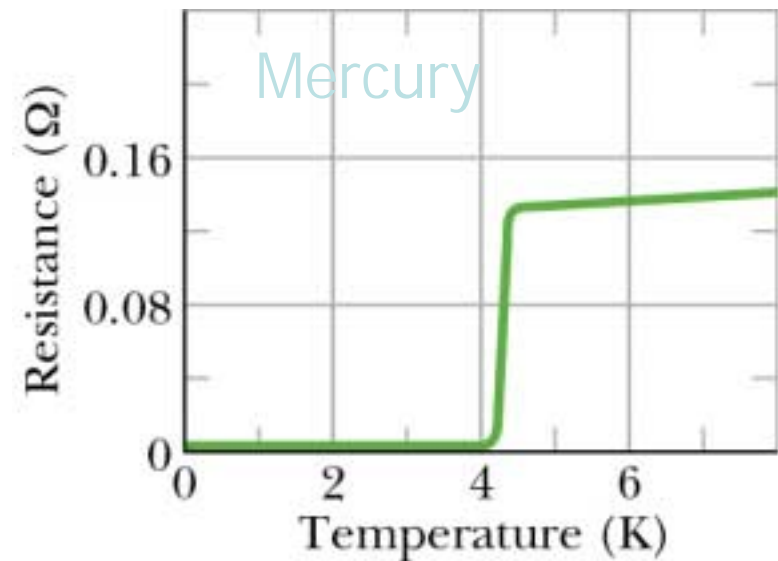
# Current (23)

- **Metal:**  $n$  is large but constant with  $T$ ,  $R \uparrow$  when  $T \uparrow$  due to increase in collision rate of charge carriers
- **Semiconductor:** Like insulator but takes less energy to free electrons
- Add charge carriers by process called doping
- **Semiconductor:**  $n$  is small but increases with  $T$ ,  $R \downarrow$  with  $T \uparrow$ , increase in  $n$  is greater than increase in collision rate



# Current (24)

- Superconductors:  $R$  goes to zero at some  $T$
- Once start charges moving no thermal losses so current forever
- Temperatures are usually very low (4-20K)





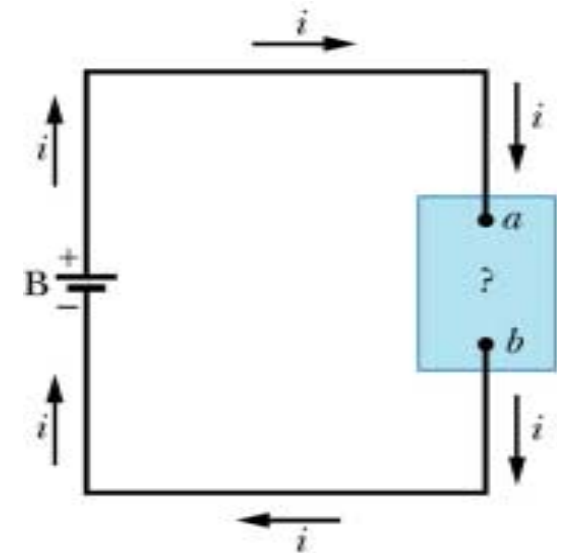
# Current (25)

- Calculate the amount of power,  $P$ , in a circuit

$$P = \frac{dU}{dt}$$

$$dU = dqV = idtV$$

$$P = iV$$



- SI unit is watt, W

$$1W = 1V \cdot A$$

# Current (26)

- Transfer potential energy,  $U$ , to some other form

$$P = iV$$

- For resistors energy is transferred to thermal energy – heat

$$R = \frac{V}{i}$$

- Use resistance definition to find

$$P = i^2 R$$

$$P = \frac{V^2}{R}$$